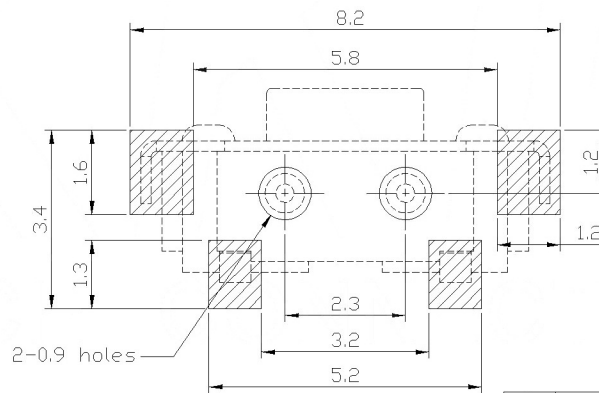
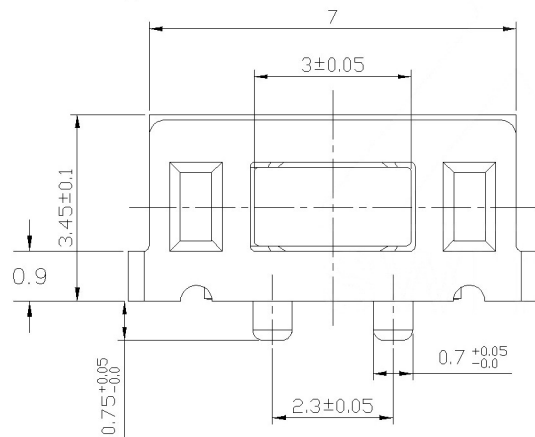
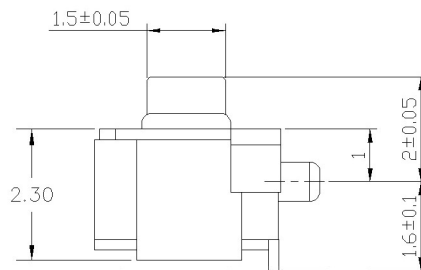
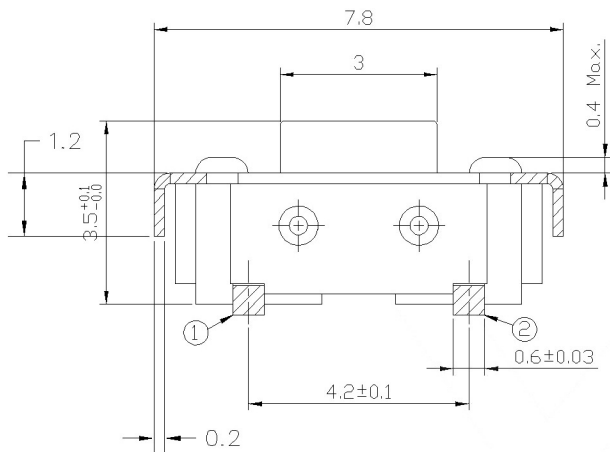
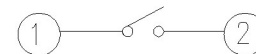




CIRCUIT DIAGRAM



SPECIFICATION

Contact Rating:	50mA,12V DC
Contact Resistance:	100mΩ max
Insulation Resistance:	100mΩ min.500V DC
Dielectric Strength:	250V AC/1minute
Travel:	0.25mm
Operating Temp:	-30℃~+85℃
Storage Temp:	-30℃~+80℃

PAPT NO	TS-1101VS-X-X-X
Operating Force	A: 100g B: 160g C: 260g
Height	H: 3.5
Fixed column	A:With B:without
Keystake	A:PA46 B:Silica gel

⑤	Terminal	—	2	Brass (0.30t)	Plating silvering	—
④	Contact	—	1	F.ag/Sus	Natural	—
③	Base	—	1	Lcp	—	—
②	Cover	—	1	Brass	Plating Nickel	—
①	Keystake	—	1	Pa46	—	—
ITEM	PAPT NAMF	TER.NO	QTY	MATERIAL	FINISHING	REMARK

							DSND		DATE		SCALE: N/A	MODEL TYPE: TACT SWITCH			
					units:	mm	DWN		DATE		VIEW: 	PART NO.:			
△ X					tolerance:		CHKD		DATE		UNIT: mm	DWG NO.:			
△ X						X.X						TS-1101VS-X-X-A			
△ X						±0.2mm						WEIGHT			
						±0.1mm						1.0g			
						±0.05mm						SHEET			
MARK	DESCRIPTION				DATE	REVISED	APPROVED	APPD		DATE		SIZE: A4	1/1		
							KOSOD TECHNOLOGY CO., LTD					REVISION			
												A0			

units: mm	
tolerance:	
X.X	±0.2mm
X.XX	±0.1mm
X.XXX	±0.05mm
UNSPECIFIED TOLERANCES	

MARK	DESCRIPTION	DATE	REVISED	APPROVED
Δx				
Δx				
Δx				